

# 2N5302 JANTX, TXV

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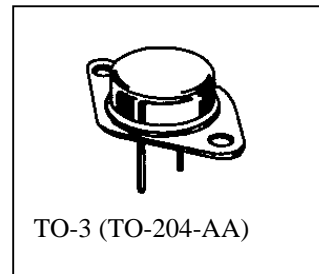
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## NPN SILICON HIGH-POWER TRANSISTOR

### MAXIMUM RATINGS

Ratings	Symbol	2N5302	2N5303	Unit
Collector-Emitter Voltage	$V_{CEO}$	60	80	Vdc
Collector-Base Voltage	$V_{CBO}$	60	80	Vdc
Emitter-Base Voltage	$V_{EBO}$	5.0		Vdc
Collector Current	$I_C$	30	20	Adc
Base Current	$I_B$	7.5		Adc
Total Power Dissipation @ $T_A = 25^{\circ}\text{C}^{(1)}$ @ $T_C = 100^{\circ}\text{C}^{(2)}$	$P_T$	5.0		W
		115		$\text{W}/^{\circ}\text{C}$
Operating & Storage Junction Temperature Range	$T_J, T_{stg}$	-65 to +200		$^{\circ}\text{C}$



### THERMAL CHARACTERISTICS

Characteristics	Symbol	Max.	Unit
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	0.875	$^{\circ}\text{C}/\text{W}$

 1) Derate linearly 28.57  $\text{mW}/^{\circ}\text{C}$  for  $T_A > 25^{\circ}\text{C}$ 

 2) Derate linearly 1.14  $\text{W}/^{\circ}\text{C}$  for  $T_C > 100^{\circ}\text{C}$ 

### ELECTRICAL CHARACTERISTICS

Characteristics	Symbol	Min.	Max.	Unit
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### OFF CHARACTERISTICS

Collector-Emitter Breakdown Current $I_C = 200 \text{ mAdc}, I_B = 0$	2N5302 2N5303	$V_{(BR)CEO}$	60 80	Vdc
Collector-Emitter Cutoff Current $V_{CE} = 60 \text{ Vdc}, I_B = 0$ $V_{CE} = 80 \text{ Vdc}, I_B = 0$	2N5302 2N5303	$I_{CEO}$	10 10	$\mu\text{Adc}$
Emitter-Base Cutoff Current $V_{EB} = 5.0 \text{ Vdc}, I_C = 0$		$I_{EBO}$	5.0	$\mu\text{Adc}$
Collector-Emitter Cutoff Current $V_{BE} = 1.5 \text{ Vdc}, V_{CE} = 60 \text{ Vdc}$ $V_{BE} = 1.5 \text{ Vdc}, V_{CE} = 80 \text{ Vdc}$	2N5302 2N5303	$I_{CEX}$	5.0 5.0	$\mu\text{Adc}$
Collector-Emitter Cutoff Current $V_{CE} = 60 \text{ Vdc}$ $V_{CE} = 80 \text{ Vdc}$	2N5302 2N5303	$I_{CBO}$	5.0 5.0	$\mu\text{Adc}$

**2N5302, 2N5303 JAN SERIES**

**ELECTRICAL CHARACTERISTICS**

Characteristics		Symbol	Min.	Max.	Unit
<b>ON CHARACTERISTICS</b>					
Forward-Current Transfer Ratio					
$I_C = 1.0 \text{ Adc}$ , $V_{CE} = 2.0 \text{ Vdc}$	All Types		40		
$I_C = 15 \text{ Adc}$ , $V_{CE} = 2.0 \text{ Vdc}$	2N5302		15	60	
$I_C = 10 \text{ Adc}$ , $V_{CE} = 2.0 \text{ Vdc}$	2N5303		15	60	
$I_C = 30 \text{ Adc}$ , $V_{CE} = 4.0 \text{ Vdc}$		$h_{FE}$	5.0		
$I_C = 20 \text{ Adc}$ , $V_{CE} = 4.0 \text{ Vdc}$			5.0		
Base-Emitter Saturation Voltage					
$I_C = 10 \text{ Adc}$ , $I_B = 1.0 \text{ Adc}$	All Types			1.7	
$I_C = 15 \text{ Adc}$ , $I_B = 1.5 \text{ Adc}$	2N5302			1.8	
$I_C = 15 \text{ Adc}$ , $I_B = 1.5 \text{ Adc}$	2N5303	$V_{BE(sat)}$		2.0	Vdc
$I_C = 20 \text{ Adc}$ , $I_B = 2.0 \text{ Adc}$	2N5302			2.5	
$I_C = 20 \text{ Adc}$ , $I_B = 4.0 \text{ Adc}$	2N5303			2.5	
Base-Emitter Non-Saturation Voltage					
$V_{CE} = 2.0 \text{ Vdc}$ ; $I_C = 15 \text{ Adc}$	2N5302			1.8	
$V_{CE} = 2.0 \text{ Vdc}$ ; $I_C = 10 \text{ Adc}$	2N5303	$V_{BE}$		1.5	Vdc
$V_{CE} = 4.0 \text{ Vdc}$ ; $I_C = 30 \text{ Adc}$	2N5302			3.0	
$V_{CE} = 4.0 \text{ Vdc}$ ; $I_C = 20 \text{ Adc}$	2N5303			2.5	
Collector-Emitter Saturation Voltage					
$I_C = 10 \text{ Adc}$ , $I_B = 1.0 \text{ Adc}$	2N5302			0.75	
$I_C = 10 \text{ Adc}$ , $I_B = 1.0 \text{ Adc}$	2N5303			1.0	
$I_C = 15 \text{ Adc}$ , $I_B = 1.5 \text{ Adc}$	2N5302	$V_{CE(sat)}$		1.0	Vdc
$I_C = 15 \text{ Adc}$ , $I_B = 1.5 \text{ Adc}$	2N5303			1.5	
$I_C = 20 \text{ Adc}$ , $I_B = 2.0 \text{ Adc}$	2N5302			2.0	
$I_C = 20 \text{ Adc}$ , $I_B = 4.0 \text{ Adc}$	2N5303			2.0	
$I_C = 40 \text{ Adc}$ , $I_B = 6.0 \text{ Adc}$	2N5302			3.0	

**DYNAMIC CHARACTERISTICS**

Magnitude of Small-Signal Short Circuit Forward Current Transfer Ratio					
$I_C = 1.0 \text{ Adc}$ , $V_{CE} = 10 \text{ Vdc}$ , $f = 1.0 \text{ MHz}$		$ h_{fe} $	2.0	40	
Output Capacitance					
$V_{CB} = 10 \text{ Vdc}$ , $I_E = 0$ , $100 \text{ kHz} \leq f \leq 1.0 \text{ MHz}$		$C_{obo}$		800	pF

**SWITCHING CHARACTERISTICS**

Delay Time	$V_{CC} = 30 \text{ Vdc}$ ;	$t_d$		0.2	$\mu\text{s}$
Rise Time	$I_C = 10 \text{ Adc}$ ;	$t_r$		0.9	$\mu\text{s}$
Storage Time	$I_B = 1.0 \text{ Adc}$	$t_s$		2.0	$\mu\text{s}$
Fall Time		$t_f$		1.0	$\mu\text{s}$

**SAFE OPERATING AREA**

<b>DC Tests: <math>T_C = 25^{\circ}\text{C}</math>, 1 Cycle, <math>t \geq 1.0 \text{ s}</math></b>	
<b>Test 1</b>	
$V_{CE} = 6.67 \text{ Vdc}$ , $I_C = 30 \text{ Adc}$	2N5302
$V_{CE} = 10 \text{ Vdc}$ , $I_C = 20 \text{ Adc}$	2N5303
<b>Test 2</b>	
$V_{CE} = 20 \text{ Vdc}$ , $I_C = 10 \text{ Adc}$	2N5302; 2N5303
<b>Test 3</b>	
$V_{CE} = 40 \text{ Vdc}$ , $I_C = 3.0 \text{ Adc}$	2N5302; 2N5303
<b>Test 4</b>	
$V_{CE} = 50 \text{ Vdc}$ , $I_C = 600 \text{ mAdc}$	2N5302
$V_{CE} = 60 \text{ Vdc}$ , $I_C = 600 \text{ mAdc}$	2N5303
<b>Clamped Switching: <math>T_A = 25^{\circ}\text{C}</math>, <math>V_{CE} = 15 \text{ Vdc}</math></b>	
Clamp Voltage = $60 \text{ Vdc}$ , $I_C = 30 \text{ Adc}$	2N5302
Clamp Voltage = $80 \text{ Vdc}$ , $I_C = 20 \text{ Adc}$	2N5303